TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX541F,TC74LCX541FW,TC74LCX541FT

Low-Voltage Octal Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX541F/FW/FT is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

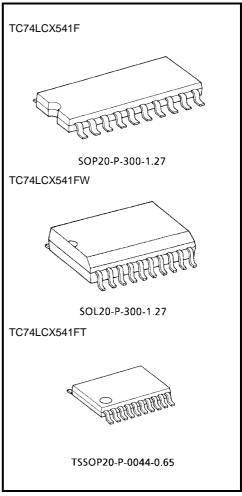
The TC74LCX541F/FW/FT is a non-inverting 3-state buffer having two active-low output enables. When either $\overline{OE}1$ or $\overline{OE}2$ are high, the terminal outputs are in the high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

Features

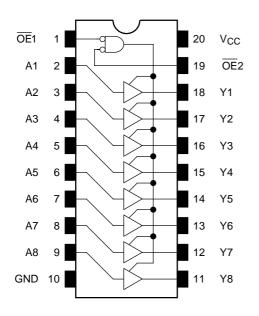
- Low-voltage operation: V_{CC} = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 6.5 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 541 type

Note: xxxFW (JEDEC SOP) is not available in Japan.

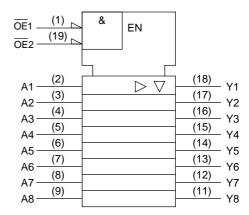


Weight SOP20-P-300-1.27: 0.22 g (typ.) SOL20-P-300-1.27: 0.46 g (typ.) TSSOP20-P-0044-0.65: 0.08 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

	Inputs					
OE1	OE2	Outputs				
Н	Х	Х	Z			
Х	Н	Х	Z			
L	L	Н	Н			
L	L	L	L			

X: Don't care

Z: High impedance

Maximum Ratings

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 1)	
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
		(Note 2)	
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note 3)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100 r	
Storage temperature	T _{stg}	-65 to 150	

Note 1: Output in OFF state

Note 2: High or low state. IOUT absolute maximum rating must be observed.

2

Note 3: Vout < GND, Vout > Vcc



Recommended Operating Conditions

Characteristics	Symbol Rating		Unit		
Power supply voltage	V _{CC}	2.0 to 3.6	V		
Power supply voltage	vcc vcc	1.5 to 3.6 (Note 4)	V		
Input voltage	V _{IN}	0 to 5.5	V		
Output voltage	V	0 to 5.5 (Note 5)	V		
Output voltage	Vout	0 to V _{CC} (Note 6)]		
Output ourropt	la/la.	±24 (Note 7)	mA		
Output current	I _{OH} /I _{OL}	±12 (Note 8)	mA		
Operating temperature	T _{opr}	-40 to 85	°C		
Input rise and fall time	dt/dv	0 to 10 (Note 9)	ns/V		

Note 4: Data retention only

Note 5: Output in OFF state

Note 6: High or low state

Note 7: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 8: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 9: $V_{IN} = 0.8 \text{ to } 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Symbol	Test Condition			Min	Max	Unit
Onaracionsi	.103	Oymbor	root condition		V _{CC} (V)	IVIIII	IVIAX	Offic
Input voltage	H-level	VIH	_	_	2.7 to 3.6	2.0	_	V
input voltage	L-level	V _{IL}	_	_	2.7 to 3.6	_	0.8	v
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2		
	H-level	Voh	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -12 mA	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage				I _{OH} = -24 mA	3.0	2.2	_	V
		V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	2.7 to 3.6	_	0.2	
	L-level			I _{OL} = 12 mA	2.7	_	0.4	
	L-level		VOL	AOF AIM = AIH OLAIF	I _{OL} = 16 mA	3.0	_	0.4
			lo	I _{OL} = 24 mA	3.0	_	0.55	
Input leakage current		I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μΑ
2 state output off state	current	loa	$V_{IN} = V_{IH}$ or V_{IL}		2.7 to 3.6		15.0	_
3-state output off-state current		l _{OZ}	V _{OUT} = 0 to 5.5 V		2.7 10 3.0	_	±5.0	μА
Power off leakage curr	rent	I _{OFF}	$V_{IN}/V_{OUT} = 5.5 \text{ V}$		0	_	10.0	μΑ
Quiescent supply current		Icc	V _{IN} = V _{CC} or GND		2.7 to 3.6	_	10.0	
Quicocent supply cure		100	$V_{IN}/V_{OUT} = 3.6 \text{ to } 5.5 \text{ V}$		2.7 to 3.6	_	±10.0	μΑ
Increase in I _{CC} per inp	out	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	500	

3



AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	\/ \(\(\) \(\)	Min	Max	Unit
	_		V _{CC} (V)			
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7		7.5	- ns
r ropagation dotay time	t _{pHL}	Tigato 1, Tigato 2	3.3 ± 0.3	1.5	6.5	
Output enable time	t _{pZL}	Figure 1, Figure 3	2.7	_	9.5	- ns
Output enable time	t _{pZH}	Trigule 1, Figure 3	3.3 ± 0.3	1.5	8.5	
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	_	8.5	ns
Output disable time	t _{pHZ}	rigure 1, rigure 3	3.3 ± 0.3	1.5	7.5	20
Output to output skew	t _{osLH}	(Note 10)	2.7	_		ns
Output to output skew	t _{osHL}	(Note 10)	3.3 ± 0.3	_	1.0	115

Note 10: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, input: $t_r = t_f = 2.5 \text{ ns}$, $C_L = 50 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic	V _{OL}	V _{OLP}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic	V _{OL}	V _{OLV}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

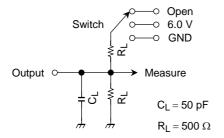
Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		3.3	7	pF
Output capacitance	C _{OUT}	_		3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$	(Note 11)	3.3	40	pF

Note 11: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t_{pLZ} , t_{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

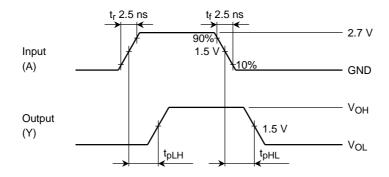


Figure 2 t_{pLH}, t_{pHL}

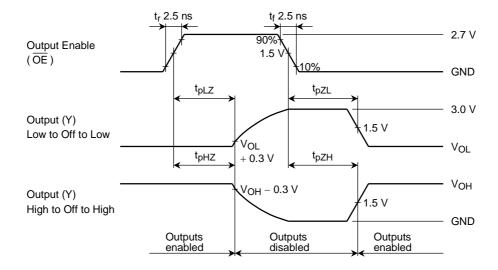
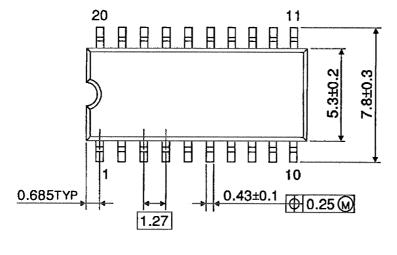
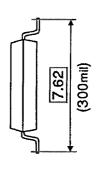


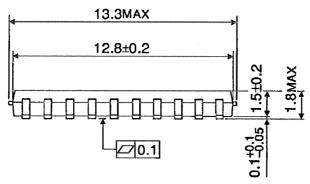
Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

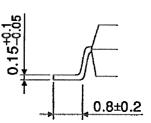
Package Dimensions

SOP20-P-300-1.27 Unit: mm









Weight: 0.22 g (typ.)

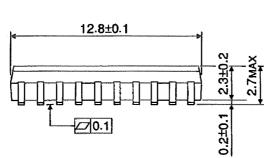
Package Dimensions

0.685TYP

SOL20-P-300-1.27

20

Unit: mm Note: This package is not available in japan. 10.3±0.2 0.42±0.07 ⊕|0.25 ₩

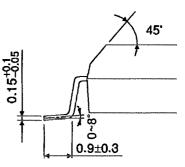


1.27

11

10

7.5±0.1

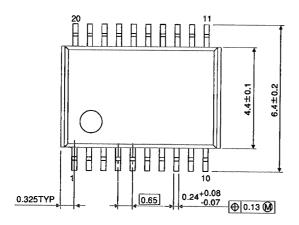


Weight: 0.46 g (typ.)

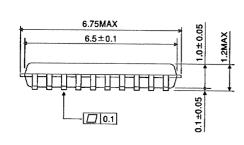
Unit: mm

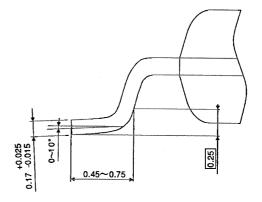
Package Dimensions

TSSOP20-P-0044-0.65









Weight: 0.08 g (typ.)

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